

# **R5541K Series**

# Low ON Resistance Nch Load Switch IC

NO.EA-319-190108

### **OUTLINE**

The R5541K is a CMOS-based dual supply voltage load switch IC. The R5541K is an ideal switch for supplying the power from the secondary power source such as the output of a step-down DC/DC converter to the load circuit. A built-in Nch. transistor with typically 18 m $\Omega$  ON resistance allows the R5541K to provide a low dropout voltage and prevents the reverse current during shutdown mode. Internally, a single IC consists of an internal voltage step-up circuit, a soft-start circuit, a thermal shutdown circuit, a chip enable circuit and a UVLO circuit.

The gate voltage of Nch. driver transistor is supplied by a soft-start circuit. The soft-start circuit is supplied by the external power source (V<sub>BIAS</sub>). Soft-start time is adjustable by connecting an external capacitor.

The R5541K is offered in an ultra-small 6-pin DFN(PLP)1216-6G package which achieve the smallest possible footprint solution on boards where area is limited.

#### **FEATURES**

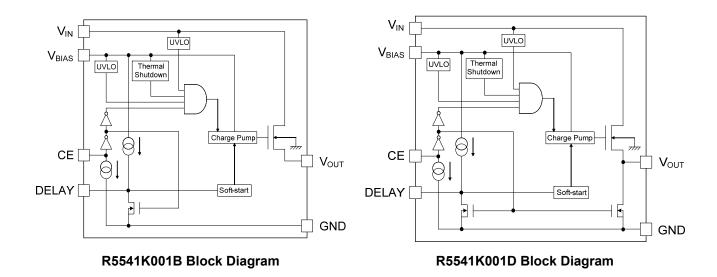
•	Supply Current ·····	• Typ. 25 $\mu$ A (I <sub>OUT</sub> = 0 mA)

- Standby Current····· Typ. 0.01 µA
- V<sub>IN</sub> Input Voltage Range··············· 0.6 V to 4.8 V
- V<sub>BIAS</sub> Input Voltage Range · · · · · · 2.5 V to 5.5 V
- Switch ON Resistance ...... Typ. 18 mΩ (V<sub>IN</sub> = 1.0 V, V<sub>BIAS</sub> = 5.0 V)
- A single Nch MOSFET Circuit
- Soft-start Function
- Thermal Shutdown Circuit
- Auto-discharge Function (R5541K001D)
- Package ...... DFN(PLP)1216-6G

#### **APPLICATIONS**

Secondary Power Source for hand-held communication equipments and laptop PCs

# **BLOCK DIAGRAMS**



# **SELECTION GUIDE**

The auto-discharge function\*1 is a user-selectable option.

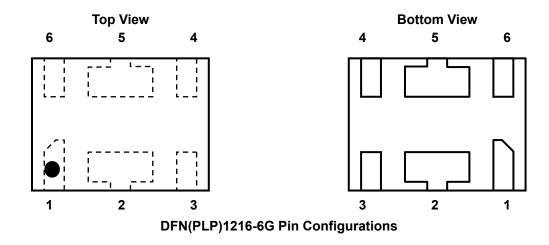
#### **Selection Guide**

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R5541K001*-E2	DFN(PLP)1216-6G	5,000 pcs	Yes	Yes

- \*: Specify the CE Pin Polarity and auto-discharge option.
  - B: Active-High, no auto-discharge function
  - D: Active-High, auto-discharge function

<sup>&</sup>lt;sup>\*1</sup> Auto-discharge function quickly lowers the output voltage to 0 V, when the chip enable signal is switched from the active mode to the standby mode, by releasing the electrical charge accumulated in the external capacitor.

# **PIN DESCRIPTION**



DFN(PLP)1216-6G Pin Description

Pin No.	Symbol	Description	
1	CE	Chip Enable Pin (Active-High)	
2	VIN	Input Pin 2*1	
3	V <sub>BIAS</sub>	Input Pin 1*1	
4	GND	Ground Pin	
5	V <sub>OUT</sub>	Output Pin	
6	DELAY	DELAY Pin for Soft-start Setting	

 $<sup>^{*1}</sup>$  V<sub>IN</sub> should be used as V<sub>IN</sub>  $\leq$  V<sub>BIAS</sub>.

# ABSOLUTE MAXIMUM RATINGS

**Absolute Maximum Ratings** 

Symbol	Item	Rating	Unit
V <sub>BIAS</sub>	V <sub>BIAS</sub> Pin Input Voltage −0.3 to 6.0		V
Vin	V <sub>IN</sub> Pin Input Voltage	−0.3 to 5.5	V
V <sub>CE</sub>	CE Pin Input Voltage	-0.3 to 6.0	V
Vouт	Vout Pin Voltage	−0.3 to V <sub>IN</sub>	V
Іоит	Output Current	3.0	Α
P <sub>D</sub>	Power Dissipation (JEDEC STD.51-7 Test Land Pattern)*1	714	mW
Tj	Junction Temperature	-40 to 125	°C
Tstg	Storage Temperature Range	−55 to 125	°C

<sup>\*1</sup> Refer to PACKAGE INFORMATION for detailed information.

#### **ABSOLUTE MAXIMUM RATINGS**

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

#### RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

### **ELECTRICAL CHARACTERISTICS**

 $V_{BIAS}$  = 5.0 V,  $V_{IN}$  = 1.0 V,  $C_{BIAS}$  = 1 μF,  $C_{IN}$  = none,  $C_{OUT}$  = 0.1 μF, unless otherwise noted. The specifications surrounded by are guaranteed by Design Engineering at −40°C ≤ Ta ≤ 85°C.

#### **R5541K Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Symbol	Item	Conditions		Min.	Тур.	Max.	Unit
V <sub>BIAS</sub>	V <sub>BIAS</sub> Pin Input Voltage			2.5		5.5	٧
V <sub>IN</sub>	V <sub>IN</sub> Pin Input Voltage			0.6		4.8	V
Ron	Switch ON Resistance	I <sub>ОUТ</sub> = 500 mA			18	28	mΩ
Iss	Supply Current	I <sub>OUT</sub> = 0 mA, V <sub>BIAS</sub> Pin			25	47	μΑ
Istandby	Standby Current	V <sub>CE</sub> = 0 V,	V <sub>BIAS</sub> Pin		0.01	0.15	μA
istandby	Standby Current	$V_{IN} = 4.8 \text{ V}, V_{BIAS} = 5.5 \text{ V}$	V <sub>IN</sub> Pin		0.01	1	μΑ
UVLO	Undervoltage Lockout	e Lockout V <sub>BIAS</sub> Pin <sup>*1</sup>		2.0		2.49	V
UVLO	Voltage	V <sub>IN</sub> Pin*2		0.3		0.59	V
T <sub>TSD</sub>	Thermal Shutdown Temperature	Junction Temperature			145		°C
T <sub>TSR</sub>	Thermal Shutdown Release Temperature	Junction Temperature			125		°C
ICEPD	CE Pull-down Current				0.4	0.8	μA
VCEH	CE Input Voltage "H"			1.0			V
Vcel	CE Input Voltage "L"					0.4	V
IDELAY	DELAY Pin Current	*3		1.25	1.5	1.8	μΑ
R <sub>LOW</sub>	Low Output Nch Tr. ON Resistance (R5541K001D)	V <sub>CE</sub> = 0 V			80		Ω

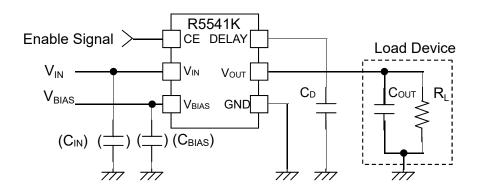
All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition (Tj ≈ Ta = 25°C).

<sup>\*1</sup> The UVLO detector threshold and the UVLO release voltage are between the min and the max of UVLO with Typ. 90 mV hysteresis.

<sup>&</sup>lt;sup>\*2</sup> The UVLO detector threshold and the UVLO release voltage are between the min and the max of UVLO with Typ. 70 mV hysteresis.

<sup>\*3</sup> Soft-start time can be adjusted by using I<sub>DELAY</sub> and a capacitor (C<sub>D</sub>). Refer to Soft-start Function in TECHNICAL NOTES for detailed Information.

### TYPICAL APPLICATION



**R5541K Typical Application** 

### **TECHNICAL NOTES**

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed a rated voltage, a rated current or a rated power. When designing a peripheral circuit, please be fully aware of the following points.

- An input capacitor (C<sub>IN</sub>) and a bypass capacitor (C<sub>BIAS</sub>) are NOT necessarily required between the V<sub>IN</sub> pin and GND. If there is a possibility that the parasitic element (inductance) of V<sub>IN</sub> may generate spike noise, connect an appropriate capacitor (about 0.1 μF) between the V<sub>IN</sub> pin and GND.
- $V_{IN}$  and  $V_{BIAS}$  should always be used as  $V_{IN} \le V_{BIAS}$ .
- Connect the DELAY pin to a capacitor (CD) or leave the DELAY pin floating.

### SOFT-START FUNCTION

Soft-start function maintains the smooth control of the output voltage to prevent an inrush current during start-up by adjusting the soft-start time (tstart) ( $V_{OUT} = 10\%$  to 90%). tstart can be adjusted by connecting a capacitor ( $C_D$ ) between the DELAY pin and GND. The calculation of  $C_D$  is as follows.

$$C_D$$
 [nF] = 7.5 x tstart [ms] x  $I_{DELAY}$  [ $\mu$ A] /  $V_{IN}$  [V]

If  $C_D$  is not connected to the DELAY pin, leave the DELAY pin floating. If the DELAY pin is left floating, the calculation of the start-up time (tr) ( $V_{OUT} = 10\%$  to 90%) is as follows.

$$tr [ms] = 0.04 \times V_{IN} [V] (Typ.)$$

V<sub>BIAS</sub>, V<sub>IN</sub> and CE can be sequenced in any order; the device can start up with soft-start function.

### PACKAGE INFORMATION

# POWER DISSIPATION (DFN(PLP)1216-6G)

Power Dissipation  $(P_D)$  of the package is dependent on PCB material, layout, and environmental conditions. The following conditions are used in this measurement.

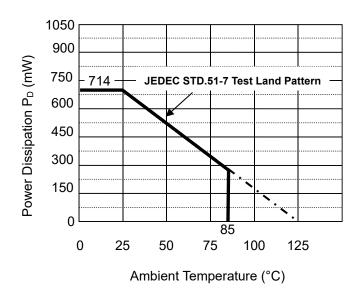
#### **Measurement Conditions**

	JEDEC STD.51-7 Test Land Pattern	
Environment Mounting on Board (Wind Velocity = 0m/s)		
Board Material	Glass Cloth Epoxy Plastic (4 Layer)	
Board Dimensions	76.2 mm × 114.3 mm × 1.6 mm	
Copper Ratio	Top side, Back side: 60 mm x 60mm, Approx.10% 2nd, 3rd layers: 74.2 mm x 74.2 mm, Approx. 100%	
Through-holes	φ 0.85 mm x 44 pcs	

#### Measurement Result

(Ta = 25°C, Tjmax = 125°C)

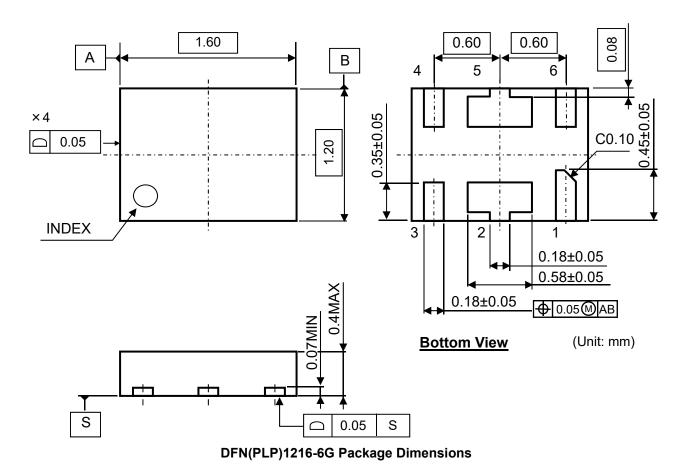
	JEDEC STD.51-7 Test Land Pattern
Power Dissipation	714 mW
Thermal	θja = (125 - 25°C) / 0.714 W = 140°C/W
Resistance	θjc = 21°C/W



**Ambient Temperature vs. Power Dissipation** 

**Measurement Board Pattern** 

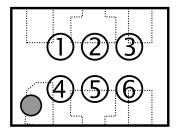
### PACKAGE DIMENSIONS (DFN(PLP)1216-6G)



# MARK SPECIFICATION (DFN(PLP)1216-6G)

①②③④: Product Code ... Refer to MARK SPECIFICATION TABLE DFN(PLP)1216-6G.

⑤⑥: Lot Number ...Alphanumeric Serial Number



DFN(PLP)1216-6G Mark Specification

# MARK SPECIFICATION TABLE (DFN(PLP)1216-6G)

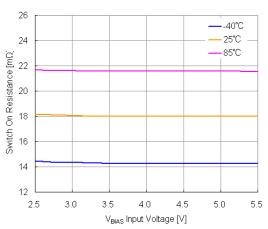
**Mark Specification Table** 

Product Name	0234
R5541K001B	D Z 0 1
R5541K001D	D Z 0 3

### TYPICAL CHARACTERISTICS

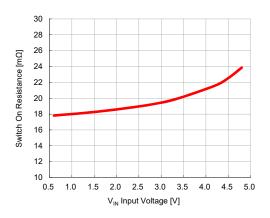
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

R5541K001x V<sub>IN</sub> = 1.0 V, I<sub>OUT</sub> = 500 mA



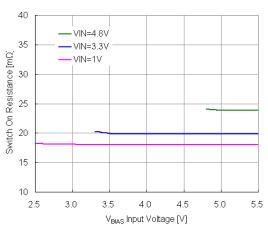
Switch On Resistance vs. VBIAS Input Voltage

R5541K001x V<sub>BIAS</sub> = 5.0 V, I<sub>OUT</sub> = 500 mA, Ta = 25°C



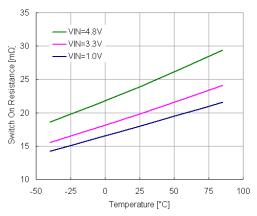
Switch On Resistance vs. V<sub>IN</sub> Input Voltage

R5541K001x I<sub>OUT</sub> = 500 mA, Ta = 25°C

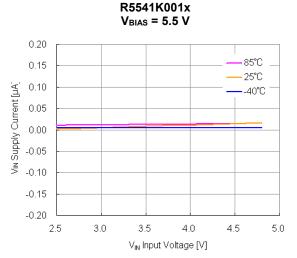


Switch On Resistance vs. VBIAS Input Voltage

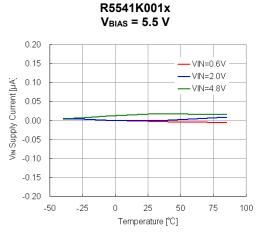
 $R5541K001x \\ V_{\text{IN}} = 1.0 \text{ V, } V_{\text{BIAS}} = 5.0 \text{ V, } I_{\text{OUT}} = 500 \text{ mA}$ 



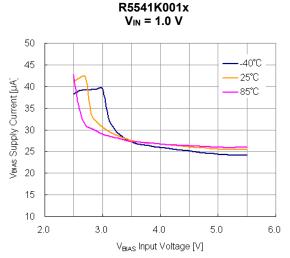
Switch On Resistance vs. Temperature



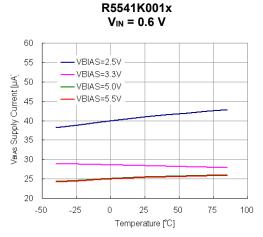
VIN Supply Current vs. VIN Input Voltage



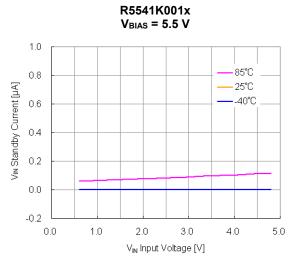
VIN Supply Current vs. Temperature



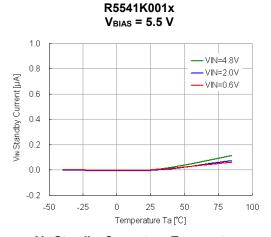
VBIAS Supply Current vs. VBIAS Input Voltage



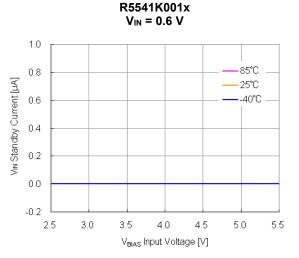
**VBIAS Supply Current vs. Temperature** 



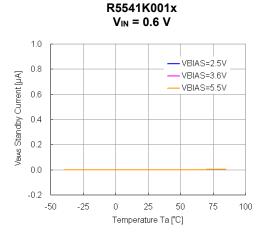
VIN Standby Current vs. VIN Input Voltage



 $V_{\text{\scriptsize IN}}$  Standby Current vs. Temperature

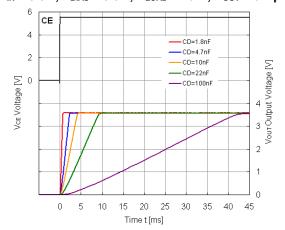


VIN Standby Current vs. VBIAS Input Voltage



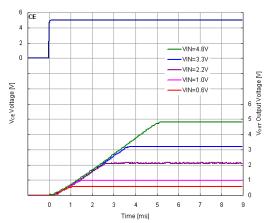
**V<sub>BIAS</sub> Standby Current vs. Temperature** 

R5541K001x Vin = 3.6 V, VBIAS = 5.5 V, RLOAD = 10  $\Omega$ , COUT = 0.1  $\mu$ F



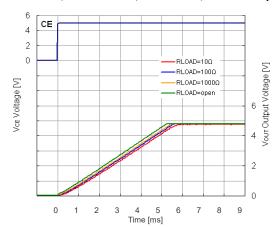
Vout Output Voltage On Time vs. DELAY Capacitance

 $\label{eq:vbias} R5541K001x$   $V_{BIAS}$  = 5.0 V,  $C_D$  = 10 nF,  $R_{LOAD}$  = 10  $\Omega,$   $C_{OUT}$  = 0.1  $\mu F$ 



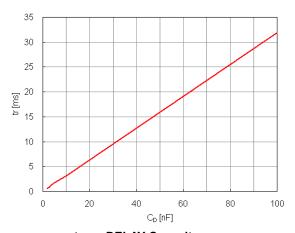
V<sub>OUT</sub> Output Voltage On Time vs. V<sub>IN</sub> Input Voltage

 $\label{eq:vin} R5541K001x$   $V_{\text{IN}}$  = 4.8 V,  $V_{\text{BIAS}}$  = 5.0 V,  $C_{D}$  = 10 nF,  $C_{\text{OUT}}$  = 0.1  $\mu\text{F}$ 



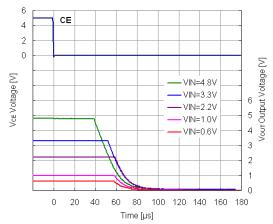
**VOUT Output Voltage On Time vs. Load Resistance** 

R5541K001x V<sub>IN</sub> = 3.6 V, V<sub>BIAS</sub> = 5.5 V, R<sub>LOAD</sub> = 10  $\Omega$ , C<sub>OUT</sub> = 0.1 $\mu$ F



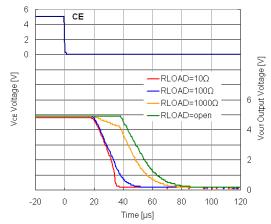
tr vs. DELAY Capacitance

 $\label{eq:vbias} R5541K001D$   $\label{vbias} V_{BIAS} = 5.0 \text{ V, } C_D = 10 \text{ nF, } C_{OUT} = 0.1 \text{ } \mu\text{F}$ 



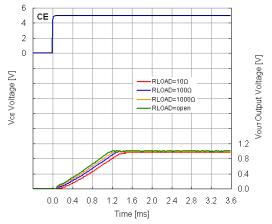
**V<sub>OUT</sub> Output Voltage Off Time vs. V<sub>IN</sub> Input Voltage** 

 $\label{eq:vin} R5541K001D$   $V_{\text{IN}}$  = 4.8 V,  $V_{\text{BIAS}}$  = 5.0 V,  $C_{D}$  = 10 nF,  $C_{\text{OUT}}$  = 0.1  $\mu\text{F}$ 



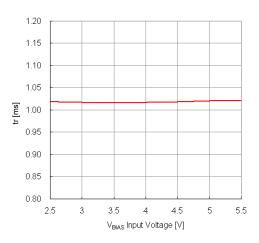
**VOUT Output Voltage Off Time vs. Load Resistance** 

 $\label{eq:vin} R5541K001x$   $V_{\text{IN}}$  = 1.0 V,  $V_{\text{BIAS}}$  = 5.5 V,  $C_{\text{D}}$  = 10 nF,  $C_{\text{OUT}}$  = 0.1  $\mu\text{F}$ 



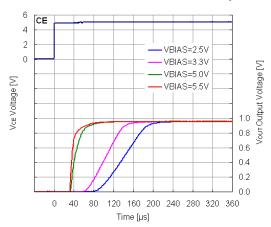
**VOUT Output Voltage On Time vs. Load Resistance** 

 $\label{eq:vin} R5541K001x$   $V_{\text{IN}}$  = 1.0 V,  $C_{\text{D}}$  = 10 nF,  $R_{\text{LOAD}}$  = 10  $\Omega,$   $C_{\text{OUT}}$  = 0.1  $\mu\text{F}$ 



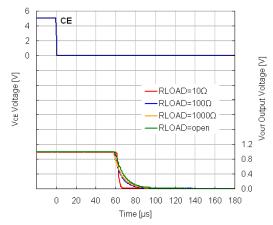
tr vs. V<sub>BIAS</sub> Input Voltage

 $\label{eq:vin} R5541K001x$   $V_{\text{IN}} = 1.0 \text{ V, } R_{\text{LOAD}} = 10 \text{ } \Omega, \text{ } C_{\text{OUT}} = 0.1 \text{ } \mu\text{F}$ 



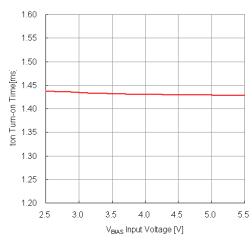
**VOUT Output Voltage On Time vs. VBIAS Input Voltage** 

 $\label{eq:vin} R5541K001D$   $V_{\text{IN}}$  = 1.0 V,  $V_{\text{BIAS}}$  = 5.5 V,  $C_{D}$  = 10 nF,  $C_{\text{OUT}}$  = 0.1  $\mu\text{F}$ 



**VOUT Output Voltage Off Time vs. Load Resistance** 

R5541K001x  $V_{\text{IN}}$  = 1.0 V,  $C_{\text{D}}$  = 10 nF,  $R_{\text{LOAD}}$  = 10  $\Omega,~C_{\text{OUT}}$  = 0.1  $\mu\text{F}$ 



ton Turn-on Time vs. VBIAS Input Voltage



- 1. The products and the product specifications described in this document are subject to change or discontinuation of production without notice for reasons such as improvement. Therefore, before deciding to use the products, please refer to Ricoh sales representatives for the latest information thereon.
- 2. The materials in this document may not be copied or otherwise reproduced in whole or in part without prior written consent of Ricoh.
- 3. Please be sure to take any necessary formalities under relevant laws or regulations before exporting or otherwise taking out of your country the products or the technical information described herein.
- 4. The technical information described in this document shows typical characteristics of and example application circuits for the products. The release of such information is not to be construed as a warranty of or a grant of license under Ricoh's or any third party's intellectual property rights or any other rights.
- 5. The products listed in this document are intended and designed for use as general electronic components in standard applications (office equipment, telecommunication equipment, measuring instruments, consumer electronic products, amusement equipment etc.). Those customers intending to use a product in an application requiring extreme quality and reliability, for example, in a highly specific application where the failure or misoperation of the product could result in human injury or death (aircraft, spacevehicle, nuclear reactor control system, traffic control system, automotive and transportation equipment, combustion equipment, safety devices, life support system etc.) should first contact us.
- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. Anti-radiation design is not implemented in the products described in this document.
- 8. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 9. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 10. There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact Ricoh sales or our distributor before attempting
- 11. Please contact Ricoh sales representatives should you have any questions or comments concerning the products or the technical information.



Ricoh is committed to reducing the environmental loading materials in electrical devices with a view to contributing to the protection of human health and the environment.

Halogen Free

Ricoh has been providing RoHS compliant products since April 1, 2006 and Halogen-free products since April 1, 2012.

#### RICOH RICOH ELECTRONIC DEVICES CO., LTD.

#### https://www.e-devices.ricoh.co.jp/en/

#### Sales & Support Offices

Ricoh Electronic Devices Co., Ltd.

Shin-Yokohama Office (International Sales)
2-3, Shin-Yokohama 3-chome, Kohoku-ku, Yokohama-shi, Kanagawa, 222-8530, Japan
Phone: +81-50-3814-7687 Fax: +81-45-474-0074

Ricoh Americas Holdings, Inc way, Suite 200 Campbell, CA 95008, U.S.A.

675 Campbell Technology Part Phone: +1-408-610-3105

Ricoh Europe (Netherlands) B.V.

Semiconductor Support Centre

Prof. W.H. Keesomlaan 1, 1183 DJ Amstelveen, The Netherlands Phone: +31-20-5474-309

Ricoh International B.V. - German Branch

Semiconductor Sales and Support Centre Oberrather Strasse 6, 40472 Düsseldorf, Germany

Phone: +49-211-6546-0

Ricoh Electronic Devices Korea Co., Ltd.

3F, Haesung Bldg, 504, Teheran-ro, Gangnam-gu, Seoul, 135-725, Korea Phone: +82-2-2135-5700 Fax: +82-2-2051-5713

Ricoh Electronic Devices Shanghai Co., Ltd.

Room 403, No.2 Building, No.690 Bibo Road, Pu Dong New District, Shanghai 201203, People's Republic of China

Phone: +86-21-5027-3200 Fax: +86-21-5027-3299

Ricoh Electronic Devices Shanghai Co., Ltd. Shenzhen Branch

1205, Block D(Jinlong Building), Kingkey 100, Hongbao Road, Luohu District,

Shenzhen, China Phone: +86-755-8348-7600 Ext 225

Ricoh Electronic Devices Co., Ltd.

Taipei office
Room 109, 10F-1, No.51, Hengyang Rd., Taipei City, Taiwan
Phone: +886-2-2313-1621/1622 Fax: +886-2-2313-1623

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

**Ricoh Electronics:** 

R5541K001D-E2 R5541K001B-E2